

**RoHS**√

### HMC431LP4 / 431LP4E

v04.1106

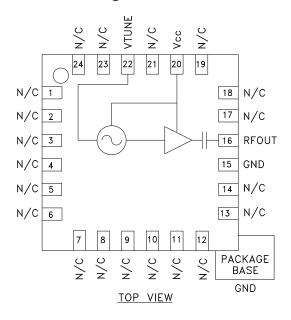
### MMIC VCO w/ BUFFER AMPLIFIER, 5.5 - 6.1 GHz

### Typical Applications

Low noise MMIC VCO w/Buffer Amplifier for C-Band applications such as:

- 802.11a & HiperLAN WLAN
- VSAT Radios
- UNII & Point-to-Point Radios

### **Functional Diagram**



#### **Features**

Pout: +2 dBm

Phase Noise: -102 dBc/Hz @100 kHz

No External Resonator Needed

Single Supply: 3V @ 27 mA

16mm<sup>2</sup> Leadless SMT Package

### **General Description**

The HMC431LP4 & HMC431LP4E are GaAs InGaP Heterojunction Bipolar Transistor (HBT) MMIC VCOs with integrated resonators, negative resistance devices, varactor diodes, and buffer amplifiers. The VCO's phase noise performance is excellent over temperature, shock, vibration and process due to the oscillator's monolithic structure. Power output is 2 dBm typical from a 3V supply voltage. The voltage controlled oscillator is packaged in a low cost leadless

QFN 4 x 4 mm surface mount package.

### Electrical Specifications, $T_A = +25^{\circ}$ C, Vcc = +3V

Parameter	Min.	Тур.	Max.	Units
Frequency Range		5.5 - 6.1		
Power Output	-1	2		dBm
SSB Phase Noise @ 100 kHz Offset, Vtune= +5V @ RF Output		-102		dBc/Hz
Tune Voltage (Vtune)	0		10	V
Supply Current (Icc) (Vcc= 3.0V)		27		mA
Tune Port Leakage Current			10	μA
Output Return Loss		6		dB
Harmonics 2nd 3rd		-15 -30		dBc dBc
Pulling (into a 2.0:1 VSWR)		9		MHz pp
Pushing @ Vtune= +5V		12		MHz/V
Frequency Drift Rate		0.8		MHz/°C

## **HMC431\* PRODUCT PAGE QUICK LINKS**

Last Content Update: 02/23/2017

### COMPARABLE PARTS 🖵

View a parametric search of comparable parts.

### **EVALUATION KITS**

· HMC431LP4 Evaluation Board

### **DOCUMENTATION**

#### **Application Notes**

 Determining the FM Bandwidth of a Wideband Varactor Tuned VCO

#### **Data Sheet**

· HMC431 Data Sheet

### REFERENCE MATERIALS 🖳

#### **Quality Documentation**

- Package/Assembly Qualification Test Report: LP4, LP4B, LP4C, LP4K (QTR: 2013-00487 REV: 04)
- Package/Assembly Qualification Test Report: Plastic Encapsulated QFN (QTR: 05006 REV: 02)
- Semiconductor Qualification Test Report: GaAs HBT-A (QTR: 2013-00228)

### DESIGN RESOURCES 🖵

- HMC431 Material Declaration
- PCN-PDN Information
- · Quality And Reliability
- Symbols and Footprints

### **DISCUSSIONS**

View all HMC431 EngineerZone Discussions.

### SAMPLE AND BUY 🖵

Visit the product page to see pricing options.

### **TECHNICAL SUPPORT**

Submit a technical question or find your regional support number.

### DOCUMENT FEEDBACK 🖳

Submit feedback for this data sheet.

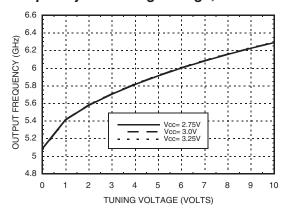
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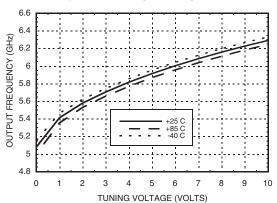


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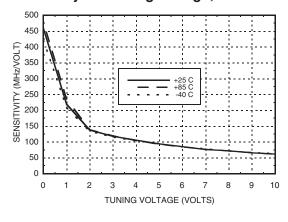
#### Frequency vs. Tuning Voltage, T= 25°C



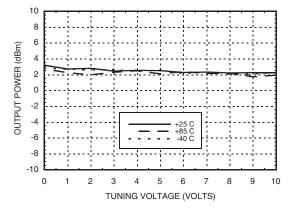
### Frequency vs. Tuning Voltage, Vcc= +3V



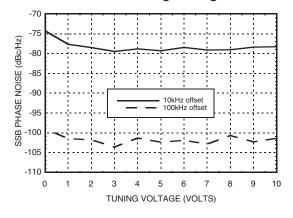
#### Sensitivity vs. Tuning Voltage, Vcc= +3V



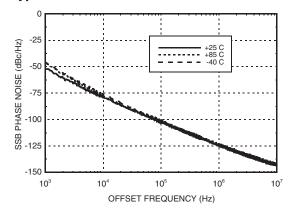
# Output Power vs. Tuning Voltage, Vcc= +3V



#### Phase Noise vs. Tuning Voltage



#### Typical SSB Phase Noise @ Vtune= +5V







### MMIC VCO w/ BUFFER AMPLIFIER, 5.5 - 6.1 GHz

#### Absolute Maximum Ratings

Vcc	+3.5 Vdc
Vtune	0 to +11V
Channel Temperature	135 °C
Continuous Pdiss (T = 85°C) (derate 6.28 mW/°C above 85°C)	565 W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 1A

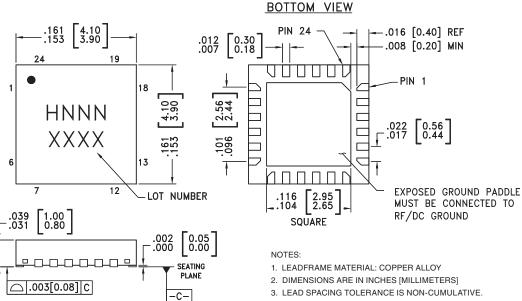
### Typical Supply Current vs. Vcc

Vcc (V)	Icc (mA)	
2.75	19	
3.0	27	
3.25	34	

Note: VCO will operate over full voltage range shown above.



### **Outline Drawing**



- 3. LEAD SPACING TOLERANCE IS NON-CUMULATIVE.
- 4. PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM. PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM.
- 5. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
- 6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.
- 7. REFER TO HITTITE APPLICATION NOT FOR SUGGESTED LAND PATTERN.

### Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [3]
HMC431LP4	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 [1]	H431 XXXX
HMC431LP4E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 [2]	H431 XXXX

- [1] Max peak reflow temperature of 235 °C
- [2] Max peak reflow temperature of 260 °C
- [3] 4-Digit lot number XXXX





# MMIC VCO w/ BUFFER AMPLIFIER, 5.5 - 6.1 GHz

### **Pin Descriptions**

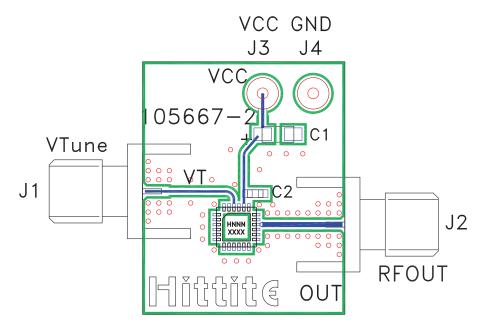
Pin Number	Function	Description	Interface Schematic
1 - 14, 17 - 19, 21, 23, 24	N/C	No Connection	
15	GND	This pin must be connected to RF & DC ground.	○ GND —
16	RFOUT	RF output (AC coupled)	—  —O RFOUT
20	Vcc	Supply Voltage Vcc= 3V	Vcc O26pF
22	VTUNE	Control Voltage Input. Modulation port bandwidth dependent on drive source impedance.	7.5nH 1500 5.2pF C;= 16-18pF
	GND	Package bottom has an exposed metal paddle that must be RF & DC grounded.	○ GND =





### MMIC VCO w/ BUFFER AMPLIFIER, 5.5 - 6.1 GHz

#### **Evaluation PCB**



#### List of Materials for Evaluation PCB 105706 [1]

Item	Description
J1 - J2	PCB Mount SMA RF Connector
J3 - J4	DC Pin
C1	4.7 μF Tantalum Capacitor
C2	10,000 pF Capacitor, 0603 Pkg.
U1	HMC431LP4 / HMC431LP4E VCO
PCB [2]	105667 Eval Board

<sup>[1]</sup> Reference this number when ordering complete evaluation PCB

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

<sup>[2]</sup> Circuit Board Material: Rogers 4350





Notes:

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